2018년 2월 6일(화), 09:00-10:45 Room F (봉래I, 6층)

F. Silicon and Group-IV Devices and Integration Technology 분과

[TF1-F] Neuromorphic Device and Application

좌장: 김경록 교수(UNIST), 양지운 교수(고려대학교)

TF1-F-1 09:00-09:15	Behavior Analysis of Gated Schottky Diode as a Synaptic Device Jong-Ho Bae, Suhwan Lim, Jai-Ho Eum, Byung-Gook Park, and Jong-Ho Lee Department of Electrical and Computer Engineering and ISRC, Seoul National University
TF1-F-2 09:15-09:30	Steep Subthreshold Swing Characteristics of Positive Feedback Diode in FinFET Technology Kyu-Bong Choi, Sung Yun Woo, and Jong-Ho Lee Department of ECE and ISRC, Seoul National University
TF1-F-3 09:30-09:45	Study on Source/Drain Metal Contact Characteristics in a Poly-Si Reconfigurable Field Effect Transistor Jai-Ho Eum, Jong-Ho Bae, and Jong-Ho Lee Department of Electrical and Computer Engineering, ISRC, Seoul National University
TF1-F-4 09:45-10:00	Neuromorphic Behaviors of HfO ₂ ReRAM by Pulse Frequency Modulation Dong Keun Lee ¹ , Min-Hwi Kim ¹ , Suhyun Bang ¹ , Tae-Hyeon Kim ¹ , Yeon-Joon Choi ¹ , Seongjae Cho ² , and Byung-Gook Park ¹ ¹ ISRC and Department of Electrical and Computer Engineering, Seoul National University, ² Department of Electronics Engineering, Gachon University
TF1-F-5 10:00-10:15	Implementation of Neuromorphic System with Neuron Circuit Retaining Overflow Jeong-Jun Lee, Jungjin Park, Sungmin Hwang, and Byung-Gook Park Department of Electrical Engineering, Seoul National University
TF1-F-6 10:15-10:30	Classification for Grayscale Images Using Supervised Spike Rate-Based Learning Seongbin Oh, Chul-Heung Kim, SooChang Lee, Byung-Gook Park, and Jong-Ho Lee Department of Electrical and Computer Engineering, ISRC, Seoul National University
TF1-F-7 10:30-10:45	An Analysis of Hot Carrier Injection in Asymmetric Dual Gate Structure Taejin Jang, Myung-Hyun Baek, and Byung-Gook Park Department of Electrical Engineering, Seoul National University